

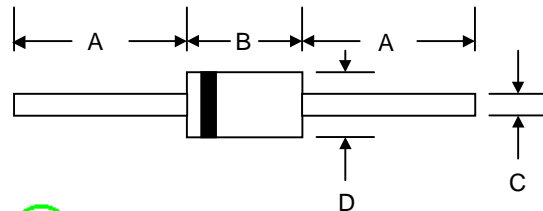
Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

Features

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * 175 Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

* *In compliance with EU RoHs 2002/95/EC directives*
 The marking is indicated by part no. with. "M". ex:SR5150M



DO-201AD		
Dim	Min	Max
A	25.4	—
B	7.20	9.50
C	1.20	1.30
D	4.80	5.30
All Dimensions in mm		

MAXIMUM RATINGS

Characteristic	Symbol	SR5150	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	150	V
RMS Reverse Voltage	$V_{R(RMS)}$	105	V
Average Rectifier Forward Current Total Device (Rated V_R), $T_C=100$	$I_{F(AV)}$	5	A
Peak Repetitive Forward Current (Rate V_R , Square Wave, 20kHz)	I_{FM}	10	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfwave, single phase, 60Hz)	I_{FSM}	125	A
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +175	

ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	SR5150	Unit
Maximum Instantaneous Forward Voltage ($I_F=5.0$ Amp $T_C=25$) ($I_F=5.0$ Amp $T_C=125$)	V_F	0.95 0.85	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C=25$) (Rated DC Voltage, $T_C=125$)	I_R	0.5 10	mA

FIG-1 FORWARD CURRENT DERATING CURVE

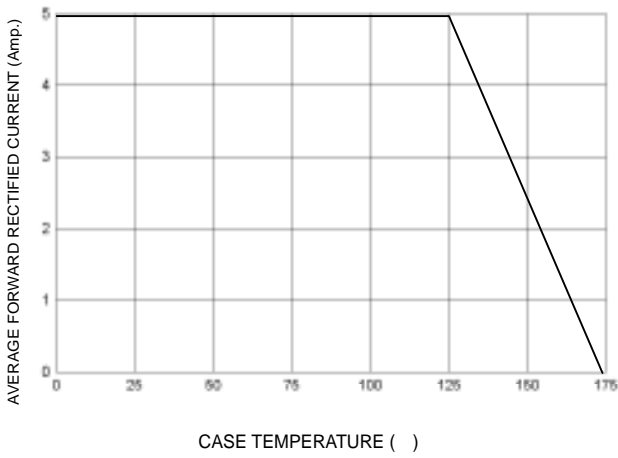


FIG-2 TYPICAL FORWARD CHARACTERISTICS

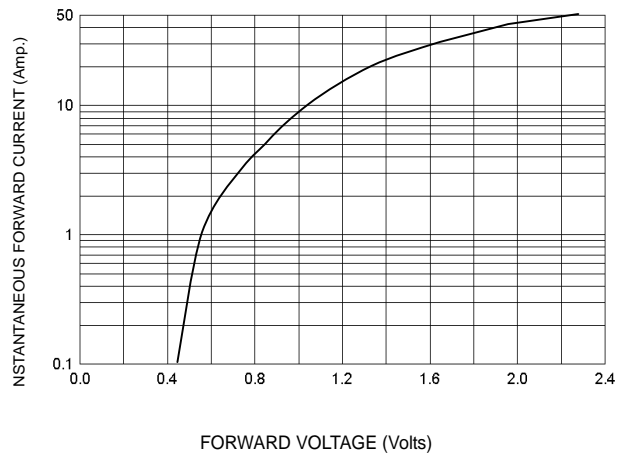


FIG-3 TYPICAL REVERSE CHARACTERISTICS

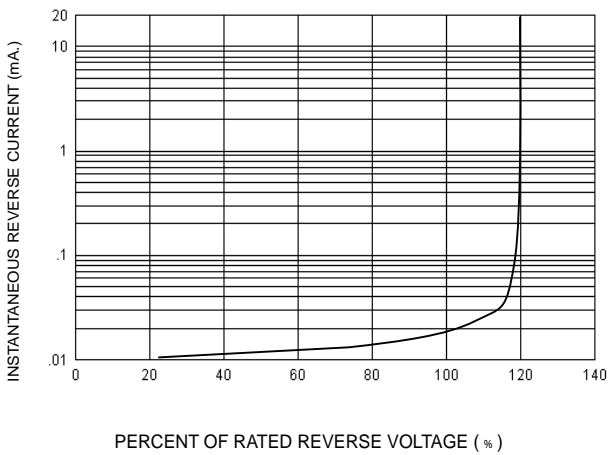


FIG-4 TYPICAL JUNCTION CAPACITANCE

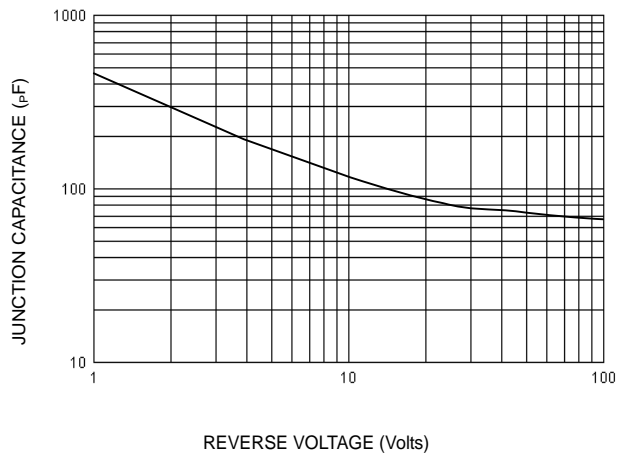


FIG-5 PEAK FORWARD SURGE CURRENT

